# NSN 5961-01-019-3581

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## Inclosure Material:

Metal

## **Overall Length:**

Between 0.460 inches and 0.535 inches

## Mounting Facility Quantity:

1

## Internal Configuration:

Junction contact

## Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-63

## **Mounting Method:**

Threaded stud

Features Provided:

Hermetically sealed case

### **Overall Width Across Flats:**

Between 0.855 inches and 0.875 inches

### Thread Size:

0.313 inches

## Semiconductor Material:

Silicon

## Voltage Rating In Volts Per Characteristic:

300.0 collector to base voltage/static/emitter open and 250.0 collector to emitter voltage/static/base open and 10.0 emitter to base voltage, static, collector open

## **Current Rating Per Characteristic:**

30.00 amperes source cutoff current

### **Power Rating Per Characteristic:**

200.0 watts small-signal input power, common-collector preset

## Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

### **Special Features:**

Junction pattern arrangement: npn

### **Thread Series Designator:**

Unf

### **Terminal Type And Quantity:**

3 tab, solder lug

### Shelf Life:

N/a

## Unit Of Measure:

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### Demilitarization:

No

## Fiig:

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